

FORM PTO 1449 (modified)  U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE			ATTY DOCKET NO. <b>03500.015719</b>		APPLICATION NO. <b>09/940,575</b>	
LIST OF REFERENCES CITED BY APPLICANT(S) (Use several sheets if necessary)			APPLICANT <b>Tohru DEN</b>			
			FILING DATE <b>August 29, 2001</b>		GROUP <b>1773</b>	

  

U.S. PATENT DOCUMENTS						
*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
<i>SK</i>	5,155,093	10/13/1992	Den, et al.	505	1	
<i>SK</i>	5,764,567	06/09/1998	Parkin	365	173	
<i>SK</i>	6,139,713	10/31/2000	Masuda, et al.	205	206	
<i>SK</i>	6,278,231 B1	08/21/2001	Iwasaki, et al.	313	310	

  

FOREIGN PATENT DOCUMENTS						
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION YES/NO/ OR ABSTRACT
<i>SK</i>	JP 10-190090	07/21/1998	Japan			Abstract & English Counterpart
<i>SK</i>	JP 10-283618	10/23/1998	Japan			Abstract
<i>SK</i>	JP 11-224422	08/17/1999	Japan			Abstract

  

OTHER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pages, Etc.)	
<i>SK</i>	<u>Furneaux, et al.</u> , "The Formation of Controlled-Porosity Membranes from Anodically Oxidized Aluminium," Nature, International Weekly Journal of Science, Vol. 337, No. 6203, pp. 147-149, January 12, 1989
<i>SK</i>	<u>Masuda, et al.</u> , "Fabrication of Gold Nanodot Array Using Anodic Porous Alumina as an Evaporation Mask," Japanese Journal of Applied Physics, Vol. 35, Part 2, No. 1B, pp. L126-L129, January 15, 1996
<i>SK</i>	<u>Masuda</u> , Solid State Physics, Vol. 31, No. 5, pp. 493-499 (1996)

  

EXAMINER <i>Shoanagalla</i>	DATE CONSIDERED <i>8-18-03</i>
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

MEK/tmc

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